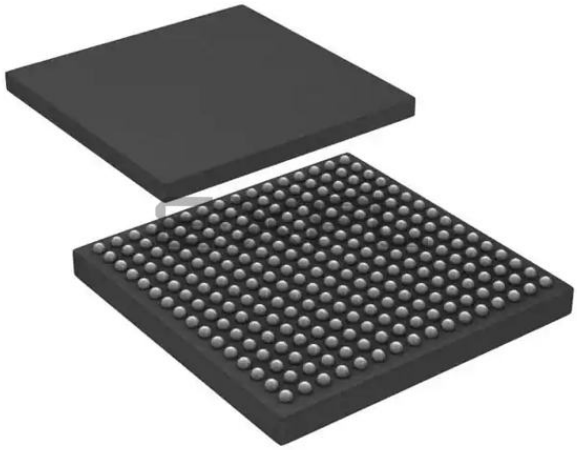

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4/M0
Core Size	32-Bit Dual-Core
Speed	204MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I²C, IrDA, Microwire, QEI, SD, SPI, SSI, SSP, UART/USART, USB, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, I²S, LCD, Motor Control PWM, POR, PWM, WDT
Number of I/O	164
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	16K x 8
RAM Size	136K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 8x10b; D/A 1x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	256-LBGA
Supplier Device Package	256-LBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/lpc4357jet256-551

4.1 Ordering options

Table 2. Ordering options

Type number	Flash total	Flash bank A	Flash bank B	Total SRAM	LCD	Ethernet	USB0 (Host, Device, OTG)	USB1 (Host, Device)/ ULPI interface	Motor control PWM	QEI	ADC channels	Temperature range[1]	GPIO
LPC4357FET256	1 MB	512 kB	512 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	F	164
LPC4357JET256	1 MB	512 kB	512 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	J	164
LPC4357JBD208	1 MB	512 kB	512 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	J	142
LPC4353FET256	512 kB	256 kB	256 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	F	164
LPC4353JET256	512 kB	256 kB	256 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	J	164
LPC4353JBD208	512 kB	256 kB	256 kB	136 kB	yes	yes	yes	yes/yes	yes	yes	8	J	142
LPC4337FET256	1 MB	512 kB	512 kB	136 kB	no	yes	yes	yes/yes	yes	yes	8	F	164
LPC4337JET256	1 MB	512 kB	512 kB	136 kB	no	yes	yes	yes/yes	yes	yes	8	J	164
LPC4337JBD144	1 MB	512 kB	512 kB	136 kB	no	yes	yes	yes/yes	yes	no	8	J	83
LPC4337JET100	1 MB	512 kB	512 kB	136 kB	no	yes	yes	yes/no	no	no	4	J	49
LPC4333FET256	512 kB	256 kB	256 kB	136 kB	no	yes	yes	yes/yes	yes	yes	8	F	164
LPC4333JET256	512 kB	256 kB	256 kB	136 kB	no	yes	yes	yes/yes	yes	yes	8	J	164
LPC4333JBD144	512 kB	256 kB	256 kB	136 kB	no	yes	yes	yes/yes	yes	no	8	J	83
LPC4333JET100	512 kB	256 kB	256 kB	136 kB	no	yes	yes	yes/no	no	no	4	J	49
LPC4327JBD144	1 MB	512 kB	512 kB	136 kB	no	no	yes	no/no	yes	no	8	J	83
LPC4327JET100	1 MB	512 kB	512 kB	136 kB	no	no	yes	no/no	no	no	4	J	49
LPC4325JBD144	768 kB	384 kB	384 kB	136 kB	no	no	yes	no/no	yes	no	8	J	83
LPC4325JET100	768 kB	384 kB	384 kB	136 kB	no	no	yes	no/no	no	no	4	J	49
LPC4323JBD144	512 kB	256 kB	256 kB	104 kB	no	no	yes	no/no	yes	no	8	J	83
LPC4323JET100	512 kB	256 kB	256 kB	104 kB	no	no	yes	no/no	no	no	4	J	49
LPC4322JBD144	512 kB	512 kB	0 kB	104 kB	no	no	yes	no/no	yes	no	8	J	83
LPC4322JET100	512 kB	512 kB	0 kB	104 kB	no	no	yes	no/no	no	no	4	J	49
LPC4317JBD144	1 MB	512 kB	512 kB	136 kB	no	no	no	no/no	yes	no	8	J	83
LPC4317JET100	1 MB	512 kB	512 kB	136 kB	no	no	no	no/no	no	no	4	J	49
LPC4315JBD144	768 kB	384 kB	384 kB	136 kB	no	no	no	no/no	yes	no	8	J	83
LPC4315JET100	768 kB	384 kB	384 kB	136 kB	no	no	no	no/no	no	no	4	J	49
LPC4313JBD144	512 kB	256 kB	256 kB	104 kB	no	no	no	no/no	yes	no	8	J	83
LPC4313JET100	512 kB	256 kB	256 kB	104 kB	no	no	no	no/no	no	no	4	J	49
LPC4312JBD144	512 kB	512 kB	0 kB	104 kB	no	no	no	no/no	yes	no	8	J	83
LPC4312JET100	512 kB	512 kB	0 kB	104 kB	no	no	no	no/no	no	no	4	J	49

[1] J = -40 °C to +105 °C; F = -40 °C to +85 °C.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P2_5	K14	D10	131	91	[3]	N; PU	I/O	**SGPIO14 —** General purpose digital input/output pin.
							I	**CTIN_2 —** SCT input 2. Capture input 2 of timer 0.
							I	**USB1_VBUS —** Monitors the presence of USB1 bus power. **Note:** This signal must be HIGH for USB reset to occur.
							I	**ADCTRIG1 —** ADC trigger input 1.
							I/O	**GPIO5[5] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							O	**T3_MAT2 —** Match output 2 of timer 3.
							O	**USB0_IND0 —** USB0 port indicator LED control output 0.
P2_6	K16	G9	137	95	[2]	N; PU	I/O	**SGPIO7 —** General purpose digital input/output pin.
							I/O	**U0_DIR —** RS-485/EIA-485 output enable/direction control for USART0.
							I/O	**EMC_A10 —** External memory address line 10.
							O	**USB0_IND0 —** USB0 port indicator LED control output 0.
							I/O	**GPIO5[6] —** General purpose digital input/output pin.
							I	**CTIN_7 —** SCT input 7.
							I	**T3_CAP3 —** Capture input 3 of timer 3.
							O	**EMC_BLS1 —** LOW active Byte Lane select signal 1.
P2_7	H14	C10	138	96	[2]	N; PU	I/O	**GPIO0[7] —** General purpose digital input/output pin. If this pin is pulled LOW at reset, the part enters ISP mode or boots from an external source (see Table 4 and Table 5).
							O	**CTOUT_1 —** SCT output 1. Match output 3 of timer 3.
							I/O	**U3_UCLK —** Serial clock input/output for USART3 in synchronous mode.
							I/O	**EMC_A9 —** External memory address line 9.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**T3_MAT3 —** Match output 3 of timer 3.
							-	**R —** Function reserved.
P2_8	J16	C6	140	98	[2]	N; PU	I/O	**SGPIO15 —** General purpose digital input/output pin. Boot pin (see Table 5).
							O	**CTOUT_0 —** SCT output 0. Match output 0 of timer 0.
							I/O	**U3_DIR —** RS-485/EIA-485 output enable/direction control for USART3.
							I/O	**EMC_A8 —** External memory address line 8.
							I/O	**GPIO5[7] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P5_4	P9	-	80	57	[2]	N; PU	I/O	**GPIO2[13] —** General purpose digital input/output pin.
							O	**MCOB0 —** Motor control PWM channel 0, output B.
							I/O	**EMC_D8 —** External memory data line 8.
							-	**R —** Function reserved.
							I	**U1_CTS —** Clear to Send input for UART 1.
							O	**T1_MAT0 —** Match output 0 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_5	P10	-	81	58	[2]	N; PU	I/O	**GPIO2[14] —** General purpose digital input/output pin.
							O	**MCOA1 —** Motor control PWM channel 1, output A.
							I/O	**EMC_D9 —** External memory data line 9.
							-	**R —** Function reserved.
							I	**U1_DCD —** Data Carrier Detect input for UART 1.
							O	**T1_MAT1 —** Match output 1 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_6	T13	-	89	63	[2]	N; PU	I/O	**GPIO2[15] —** General purpose digital input/output pin.
							O	**MCOB1 —** Motor control PWM channel 1, output B.
							I/O	**EMC_D10 —** External memory data line 10.
							-	**R —** Function reserved.
							O	**U1_TXD —** Transmitter output for UART 1.
							O	**T1_MAT2 —** Match output 2 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P5_7	R12	-	91	65	[2]	N; PU	I/O	**GPIO2[7] —** General purpose digital input/output pin.
							O	**MCOA2 —** Motor control PWM channel 2, output A.
							I/O	**EMC_D11 —** External memory data line 11.
							-	**R —** Function reserved.
							I	**U1_RXD —** Receiver input for UART 1.
							O	**T1_MAT3 —** Match output 3 of timer 1.
							-	**R —** Function reserved.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
P6_11	H12	C9	143	101	[2]	N; PU	I/O	**GPIO3[7] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**EMC_CKEOUT0 —** SDRAM clock enable 0.
							-	**R —** Function reserved.
							O	**T2_MAT3 —** Match output 3 of timer 2.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P6_12	G15	-	145	103	[2]	N; PU	I/O	**GPIO2[8] —** General purpose digital input/output pin.
							O	**CTOUT_7 —** SCT output 7. Match output 3 of timer 1.
							-	**R —** Function reserved.
							O	**EMC_DQMOUT0 —** Data mask 0 used with SDRAM and static devices.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
P7_0	B16	-	158	110	[2]	N; PU	I/O	**GPIO3[8] —** General purpose digital input/output pin.
							O	**CTOUT_14 —** SCT output 14. Match output 2 of timer 3.
							-	**R —** Function reserved.
							O	**LCD_LE —** Line end signal.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							I/O	**SGPIO4 —** General purpose digital input/output pin.
P7_1	C14	-	162	113	[2]	N; PU	I/O	**GPIO3[9] —** General purpose digital input/output pin.
							O	**CTOUT_15 —** SCT output 15. Match output 3 of timer 3.
							I/O	**I2S0_TX_WS —** Transmit Word Select. It is driven by the master and received by the slave. Corresponds to the signal WS in the *I^2S-bus specification*.
							O	**LCD_VD19 —** LCD data.
							O	**LCD_VD7 —** LCD data.
							-	**R —** Function reserved.
							O	**U2_TXD —** Transmitter output for USART2.
							I/O	**SGPIO5 —** General purpose digital input/output pin.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
PD_11	N9	-	88	-	[2]	N; PU	-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**$\overline{\text{EMC\_CS3}}$ —** LOW active Chip Select 3 signal.
							-	**R —** Function reserved.
							I/O	**GPIO6[25] —** General purpose digital input/output pin.
							I/O	**USB1_ULPI_D0 —** ULPI link bidirectional data line 0.
							O	**CTOUT_14 —** SCT output 14. Match output 2 of timer 3.
							-	**R —** Function reserved.
PD_12	N11	-	94	-	[2]	N; PU	-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**$\overline{\text{EMC\_CS2}}$ —** LOW active Chip Select 2 signal.
							-	**R —** Function reserved.
							I/O	**GPIO6[26] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							O	**CTOUT_10 —** SCT output 10. Match output 3 of timer 3.
							-	**R —** Function reserved.
PD_13	T14	-	97	-	[2]	N; PU	-	**R —** Function reserved.
							I	**CTIN_0 —** SCT input 0. Capture input 0 of timer 0, 1, 2, 3.
							O	**$\overline{\text{EMC\_BLS2}}$ —** LOW active Byte Lane select signal 2.
							-	**R —** Function reserved.
							I/O	**GPIO6[27] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							O	**CTOUT_13 —** SCT output 13. Match output 3 of timer 3.
							-	**R —** Function reserved.
PD_14	R13	-	99	-	[2]	N; PU	-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**$\overline{\text{EMC\_DYCS2}}$ —** SDRAM chip select 2.
							-	**R —** Function reserved.
							I/O	**GPIO6[28] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							O	**CTOUT_11 —** SCT output 11. Match output 3 of timer 2.
							-	**R —** Function reserved.

Table 3. Pin description *…continued*

Pin name	LBGA256	TFBGA100	LQFP208	LQFP144		Reset state [1]	Type	Description
PE_14	C15	-	-	-	[2]	N; PU	-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**EMC_DYCS3 —** SDRAM chip select 3.
							I/O	**GPIO7[14] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
PE_15	E13	-	-	-	[2]	N; PU	-	**R —** Function reserved.
							O	**CTOUT_0 —** SCT output 0. Match output 0 of timer 0.
							I/O	**I2C1_SCL —** I^2C1 clock input/output (this pin does not use a specialized I2C pad).
							O	**EMC_CKEOUT3 —** SDRAM clock enable 3.
							I/O	**GPIO7[15] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
PF_0	D12	-	159	-	[2]	O; PU	I/O	**SSP0_SCK —** Serial clock for SSP0.
							I	**GP_CLKIN —** General purpose clock input to the CGU.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							-	**R —** Function reserved.
							O	**I2S1_TX_MCLK —** I2S1 transmit master clock.
PF_1	E11	-	-	-	[2]	N; PU	-	**R —** Function reserved.
							-	**R —** Function reserved.
							I/O	**SSP0_SSEL —** Slave Select for SSP0.
							-	**R —** Function reserved.
							I/O	**GPIO7[16] —** General purpose digital input/output pin.
							-	**R —** Function reserved.
							I/O	**SGPIO0 —** General purpose digital input/output pin.
							-	**R —** Function reserved.

9. Thermal characteristics

The average chip junction temperature, T_j (°C), can be calculated using the following equation:

$$T_j = T_{amb} + (P_D \times R_{th(j-a)}) \quad (1)$$

- T_{amb} = ambient temperature (°C),
- $R_{th(j-a)}$ = the package junction-to-ambient thermal resistance (°C/W)
- P_D = sum of internal and I/O power dissipation

The internal power dissipation is the product of I_{DD} and V_{DD}. The I/O power dissipation of the I/O pins is often small and many times can be negligible. However it can be significant in some applications.

Table 8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{j(max)}$	maximum junction temperature	-	-	-	125	°C

Table 9. Thermal resistance (LQFP packages)

Symbol	Parameter	Conditions	Thermal resistance in °C/W ±15 %	
			LQFP144	LQFP208
$R_{th(j-a)}$	thermal resistance from junction to ambient	JEDEC (4.5 in × 4 in); still air	38	31
		Single-layer (4.5 in × 3 in); still air	50	39
$R_{th(j-c)}$	thermal resistance from junction to case	-	11	10

Table 10. Thermal resistance value (BGA packages)

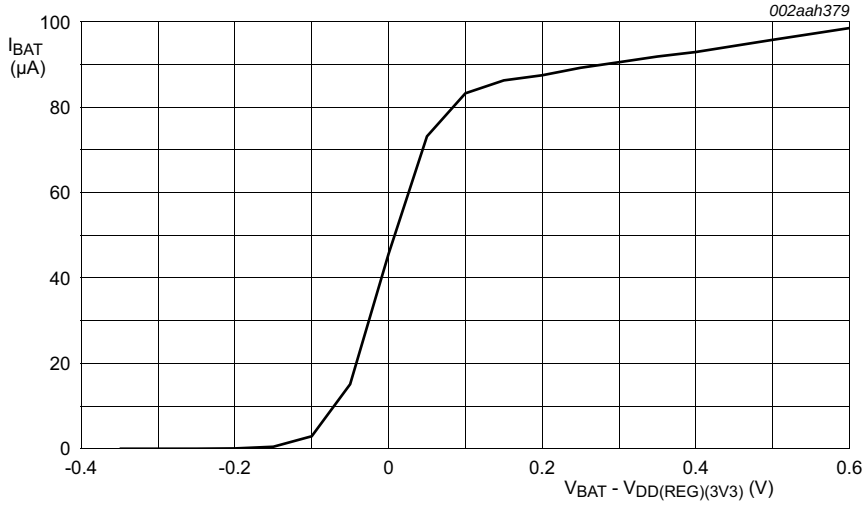
Symbol	Parameter	Conditions	Thermal resistance in °C/W ±15 %	
			LBGA256	TFBGA100
$R_{th(j-a)}$	thermal resistance from junction to ambient	JEDEC (4.5 in × 4 in); still air	29	46
		8-layer (4.5 in × 3 in); still air	24	37
$R_{th(j-c)}$	thermal resistance from junction to case		14	11

10. Static characteristics

Table 11. Static characteristics

T_{amb} = −40 °C to +105 °C, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
Supply pins							
$V_{DD(IO)}$	input/output supply voltage		[17]	2.4	-	3.6	V
$V_{DD(REG)(3V3)}$	regulator supply voltage (3.3 V)		[2]	2.4	-	3.6	V
$V_{DDA(3V3)}$	analog supply voltage (3.3 V)	on pin VDDA		2.4	-	3.6	V
		on pins USB0_VDDA3V3_ DRIVER and USB0_VDDA3V3		3.0	3.3	3.6	V
V_{BAT}	battery supply voltage		[2]	2.4	-	3.6	V
$V_{prog(pf)}$	polyfuse programming voltage	on pin VPP (for OTP)	[3]	2.7	-	3.6	V
$I_{prog(pf)}$	polyfuse programming current	on pin VPP; OTP programming time ≤ 1.6 ms		-	-	30	mA
$I_{DD(REG)(3V3)}$	regulator supply current (3.3 V)	Active mode; ARM Cortex-M0 core in reset; code `while(1){}` executed from RAM; all peripherals disabled; PLL1 enabled					
		CCLK = 12 MHz	[4]	-	10	-	mA
		CCLK = 60 MHz	[4]		28	-	mA
		CCLK = 120 MHz	[4]	-	51	-	mA
		CCLK = 180 MHz	[4]	-	74	-	mA
		CCLK = 204 MHz	[4]	-	83	-	mA
$I_{DD(REG)(3V3)}$	regulator supply current (3.3 V)	after WFE/WFI instruction executed from RAM; all peripherals disabled; ARM Cortex-M0 core in reset					
		sleep mode	[4][5]	-	8.8	-	mA
		deep-sleep mode	[4]	-	145	-	µA
		power-down mode	[4]	-	23	-	µA
		deep power-down mode	[4][6]	-	0.05	-	µA
		deep power-down mode; VBAT floating	[4]	-	3.0	-	µA
I_{BAT}	battery supply current	V_{BAT} = 3.0 V; $V_{DD(REG)(3V3)}$ = 3.3 V	[7]	-		0.1	nA



Conditions: $V_{DD(REG)(3V3)}$ = 3.0 V; V_{BAT} = 2.6 V to 3.6 V; CCLK = 12 MHz.

Remark: The recommended operating condition for the battery supply is $V_{DD(REG)(3V3)} > V_{BAT} + 0.2$ V.

Fig 19. Typical battery supply current in Active mode

10.2 Peripheral power consumption

The typical power consumption at T = 25 °C for each individual peripheral is measured as follows:

1. Enable all branch clocks and measure the current $I_{DD(REG)(3V3)}$.
2. Disable the branch clock to the peripheral to be measured and keep all other branch clocks enabled.
3. Calculate the difference between measurement 1 and 2. The result is the peripheral power consumption.

Table 12. Peripheral power consumption

Peripheral	Branch clock	$I_{DD(REG)(3V3)}$ in mA	
		Branch clock frequency = 48 MHz	Branch clock frequency = 96 MHz
M0 core	CLK_M4_M0APP	3.3	6.6
I2C1	CLK_APB3_I2C1	0.01	0.01
I2C0	CLK_APB1_I2C0	< 0.01	0.02
DAC	CLK_APB3_DAC	0.01	0.02
ADC0	CLK_APB3_ADC0	0.07	0.07
ADC1	CLK_APB3_ADC1	0.07	0.07
CAN0	CLK_APB3_CAN0	0.17	0.17
CAN1	CLK_APB1_CAN1	0.16	0.15
MOTOCON	CLK_APB1_MOTOCON	0.04	0.04
I2S	CLK_APB1_I2S	0.09	0.08
SPIFI	CLK_SPIFI, CLK_M4_SPIFI	1.14	2.29

11.7 GPCLKIN

Table 22. Dynamic characteristic: GPCLKIN

T_{amb} = 25 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V

Symbol	Parameter	Min	Typ	Max	Unit
GP_CLKIN	input frequency	-	-	25	MHz

11.8 I/O pins

Table 23. Dynamic characteristic: I/O pins[1]

T_{amb} = −40 °C to +105 °C; 2.7 V ≤ $V_{DD(IO)}$ ≤ 3.6 V.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Standard I/O pins - normal drive strength							
t_r	rise time	pin configured as output; EHS = 1	[2][3]	1.0	-	2.5	ns
t_f	fall time	pin configured as output; EHS = 1	[2][3]	0.9	-	2.5	ns
t_r	rise time	pin configured as output; EHS = 0	[2][3]	1.9	-	4.3	ns
t_f	fall time	pin configured as output; EHS = 0	[2][3]	1.9	-	4.0	ns
t_r	rise time	pin configured as input	[4]	0.3	-	1.3	ns
t_f	fall time	pin configured as input	[4]	0.2	-	1.2	ns
I/O pins - high drive strength							
t_r	rise time	pin configured as output; standard drive mode (EHD = 0x0)	[2][5]	4.3	-	7.9	ns
t_f	fall time	pin configured as output; standard drive mode (EHD = 0x0)	[2][5]	4.7	-	8.7	ns
t_r	rise time	pin configured as output; medium drive mode (EHD = 0x1)	[2][5]	3.2	-	5.7	ns
t_f	fall time	pin configured as output; medium drive mode (EHD = 0x1)	[2][5]	3.2	-	5.5	ns
t_r	rise time	pin configured as output; high drive mode (EHD = 0x2)	[2][5]	2.9	-	4.9	ns
t_f	fall time	pin configured as output; high drive mode (EHD = 0x2)	[2][5]	2.5	-	3.9	ns
t_r	rise time	pin configured as output; ultra-high drive mode (EHD = 0x3)	[2][5]	2.8	-	4.7	ns
t_f	fall time	pin configured as output; ultra-high drive mode (EHD = 0x3)	[2][5]	2.4	-	3.4	ns
t_r	rise time	pin configured as input	[4]	0.3	-	1.3	ns
t_f	fall time	pin configured as input	[4]	0.2	-	1.2	ns
I/O pins - high-speed							
t_r	rise time	pin configured as output; EHS = 1	[2][3]	350	-	670	ps
t_f	fall time	pin configured as output; EHS = 1	[2][3]	450	-	730	ps
t_r	rise time	pin configured as output; EHS = 0	[2][3]	1.0	-	1.9	ns
t_f	fall time	pin configured as output; EHS = 0	[2][3]	1.0	-	2.0	ns
t_r	rise time	pin configured as input	[4]	0.3	-	1.3	ns
t_f	fall time	pin configured as input	[4]	0.2	-	1.2	ns

[1] Simulated data.

[2] Simulated using 10 cm of 50 Ω PCB trace with 5 pF receiver input. Rise and fall times measured between 80 % and 20 % of the full output signal level.

[3] The slew rate is configured in the system control block in the SFSP registers using the EHS bit. See the LPC43xx user manual.

[4] C_L = 20 pF. Rise and fall times measured between 90 % and 10 % of the full input signal level.

[5] The drive modes are configured in the system control block in the SFSP registers using the EHD bit. See the LPC43xx user manual.

11.9 I²C-bus

Table 24. Dynamic characteristic: I²C-bus pins

T_{amb} = −40 °C to +105 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V.[1]

Symbol	Parameter		Conditions	Min	Max	Unit
f_{SCL}	SCL clock frequency		Standard-mode	0	100	kHz
			Fast-mode	0	400	kHz
			Fast-mode Plus	0	1	MHz
t_f	fall time	[3][4][5][6]	of both SDA and SCL signals Standard-mode	-	300	ns
			Fast-mode	20 + 0.1 × C_b	300	ns
			Fast-mode Plus	-	120	ns
t_{LOW}	LOW period of the SCL clock		Standard-mode	4.7	-	µs
			Fast-mode	1.3	-	µs
			Fast-mode Plus	0.5	-	µs
t_{HIGH}	HIGH period of the SCL clock		Standard-mode	4.0	-	µs
			Fast-mode	0.6	-	µs
			Fast-mode Plus	0.26	-	µs
$t_{HD;DAT}$	data hold time	[2][3][7]	Standard-mode	0	-	µs
			Fast-mode	0	-	µs
			Fast-mode Plus	0	-	µs
$t_{SU;DAT}$	data set-up time	[8][9]	Standard-mode	250	-	ns
			Fast-mode	100	-	ns
			Fast-mode Plus	50	-	ns

[1] Parameters are valid over operating temperature range unless otherwise specified. See the I²C-bus specification *UM10204* for details.

[2] tHD;DAT is the data hold time that is measured from the falling edge of SCL; applies to data in transmission and the acknowledge.

[3] A device must internally provide a hold time of at least 300 ns for the SDA signal (with respect to the V_{IH}(min) of the SCL signal) to bridge the undefined region of the falling edge of SCL.

[4] C_b = total capacitance of one bus line in pF. If mixed with Hs-mode devices, faster fall times are allowed.

[5] The maximum t_f for the SDA and SCL bus lines is specified at 300 ns. The maximum fall time for the SDA output stage t_f is specified at 250 ns. This allows series protection resistors to be connected in between the SDA and the SCL pins and the SDA/SCL bus lines without exceeding the maximum specified t_f.

[6] In Fast-mode Plus, fall time is specified the same for both output stage and bus timing. If series resistors are used, designers should allow for this when considering bus timing.

[7] The maximum $t_{HD;DAT}$ could be 3.45 µs and 0.9 µs for Standard-mode and Fast-mode but must be less than the maximum of $t_{VD;DAT}$ or $t_{VD;ACK}$ by a transition time. This maximum must only be met if the device does not stretch the LOW period (t_{LOW}) of the SCL signal. If the clock stretches the SCL, the data must be valid by the set-up time before it releases the clock.

[8] tSU;DAT is the data set-up time that is measured with respect to the rising edge of SCL; applies to data in transmission and the acknowledge.

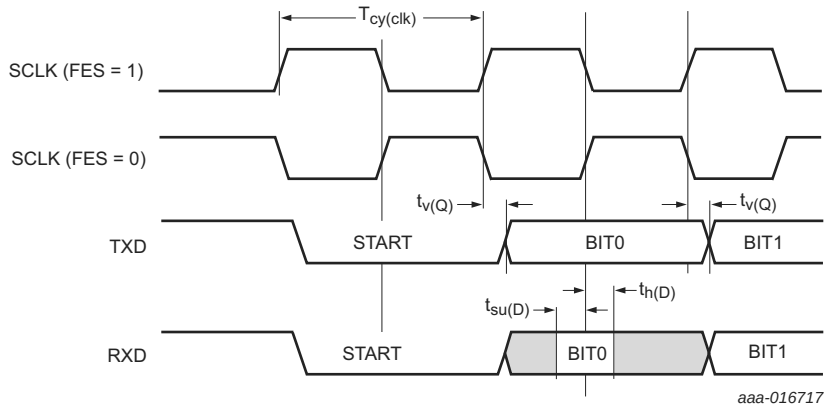


Fig 30. USART timing

11.17 External memory interface

Table 31. Dynamic characteristics: Static asynchronous external memory interface

C_L = 22 pF for EMC_Dn C_L = 20 pF for all others; T_{amb} = −40 °C to 105 °C; 2.4 V ≤ $V_{DD(REG)(3V3)}$ ≤ 3.6 V; 2.7 V ≤ $V_{DD(IO)}$ ≤ 3.6 V; values guaranteed by design; the values in the table have been calculated with WAITTURN = 0x0 in STATICWAITTURN register. Timing parameters are given for single memory access cycles. In a normal read operation, the EMC changes the address while CS is asserted which results in multiple memory accesses.

Symbol	Parameter[1]	Conditions		Min	Typ	Max	Unit
Read cycle parameters							
t_{CSLAV}	$\overline{CS}$ LOW to address valid time			−3.1	-	1.6	ns
t_{CSLOEL}	$\overline{CS}$ LOW to $\overline{OE}$ LOW time		[2] [2]	−0.6 + $T_{cy(clk)}$ × WAITOEN	-	1.3 + $T_{cy(clk)}$ × WAITOEN	ns
$t_{CSLBLSL}$	$\overline{CS}$ LOW to $\overline{BLS}$ LOW time	PB = 1		−0.7	-	1.8	ns
t_{OELOEH}	$\overline{OE}$ LOW to $\overline{OE}$ HIGH time		[2]	−0.6 + (WAITRD − WAITOEN + 1) × $T_{cy(clk)}$	-	−0.4 + (WAITRD − WAITOEN + 1) × $T_{cy(clk)}$	ns
t_{am}	memory access time			-	-	−16 + (WAITRD − WAITOEN +1) × $T_{cy(clk)}$	ns
$t_{h(D)}$	data input hold time			−16	-	-	ns
$t_{CSHBLSH}$	$\overline{CS}$ HIGH to $\overline{BLS}$ HIGH time	PB = 1		−0.4	-	1.9	ns
t_{CSHOEH}	CS HIGH to $\overline{OE}$ HIGH time			−0.4	-	1.4	ns
t_{OEHANV}	$\overline{OE}$ HIGH to address invalid	PB = 1		−2.0	-	2.6	ns
t_{CSHEOR}	$\overline{CS}$ HIGH to end of read time		[3]	−2.0	-	0	ns
t_{CSLSOR}	$\overline{CS}$ LOW to start of read time		[4]	0	-	1.8	ns
Write cycle parameters							
t_{CSLAV}	$\overline{CS}$ LOW to address valid time			−3.1	-	1.6	ns
t_{CSLDV}	$\overline{CS}$ LOW to data valid time			−3.1	-	1.5	ns
t_{CSLWEL}	$\overline{CS}$ LOW to $\overline{WE}$ LOW time	PB = 1		−1.5 + (WAITWEN + 1) × $T_{cy(clk)}$	-	0.2 + (WAITWEN + 1) × $T_{cy(clk)}$	ns
$t_{CSLBLSL}$	$\overline{CS}$ LOW to $\overline{BLS}$ LOW time	PB = 1		−0.7	-	1.8	ns
t_{WELWEH}	$\overline{WE}$ LOW to $\overline{WE}$ HIGH time	PB = 1	[2]	−0.6 + (WAITWR − WAITWEN + 1) × $T_{cy(clk)}$	-	−0.4 + (WAITWR − WAITWEN + 1) × $T_{cy(clk)}$	ns
t_{WEHDNV}	$\overline{WE}$ HIGH to data invalid time	PB = 1	[2]	−0.9 + $T_{cy(clk)}$	-	2.3 + $T_{cy(clk)}$	ns
t_{WEHEOW}	$\overline{WE}$ HIGH to end of write time	PB = 1	[2] [5]	−0.4 + $T_{cy(clk)}$	-	−0.3 + $T_{cy(clk)}$	ns
$t_{CSLBLSL}$	$\overline{CS}$ LOW to $\overline{BLS}$ LOW	PB = 0		−0.7 + (WAITWEN + 1) × $T_{cy(clk)}$	-	1.8 + (WAITWEN + 1) × $T_{cy(clk)}$	ns

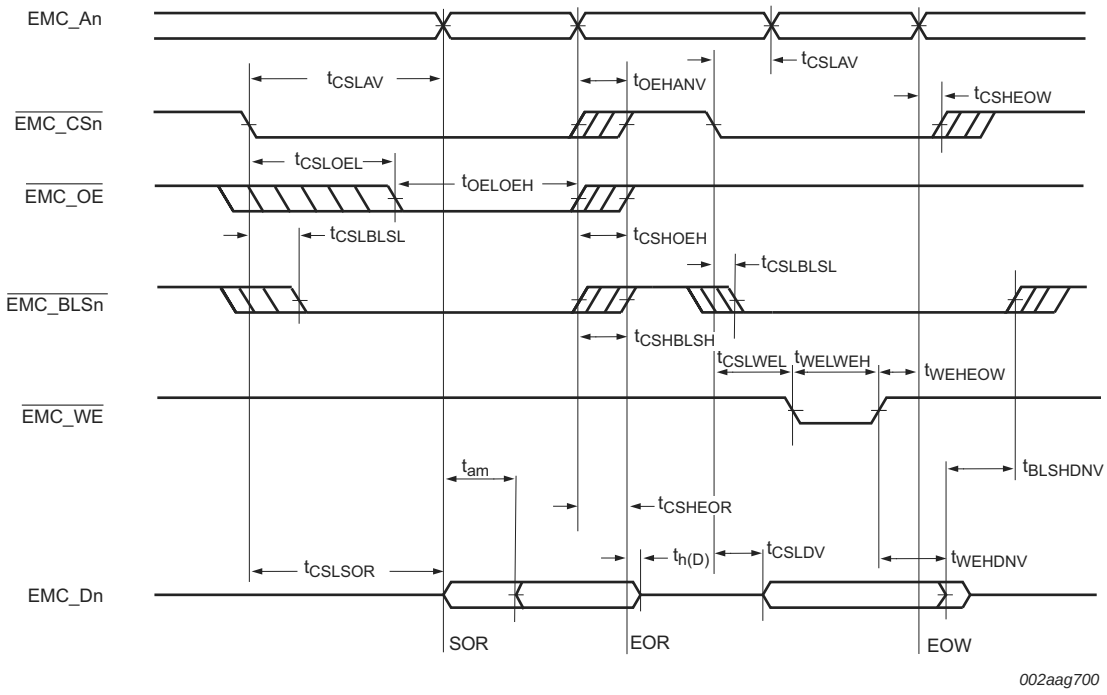
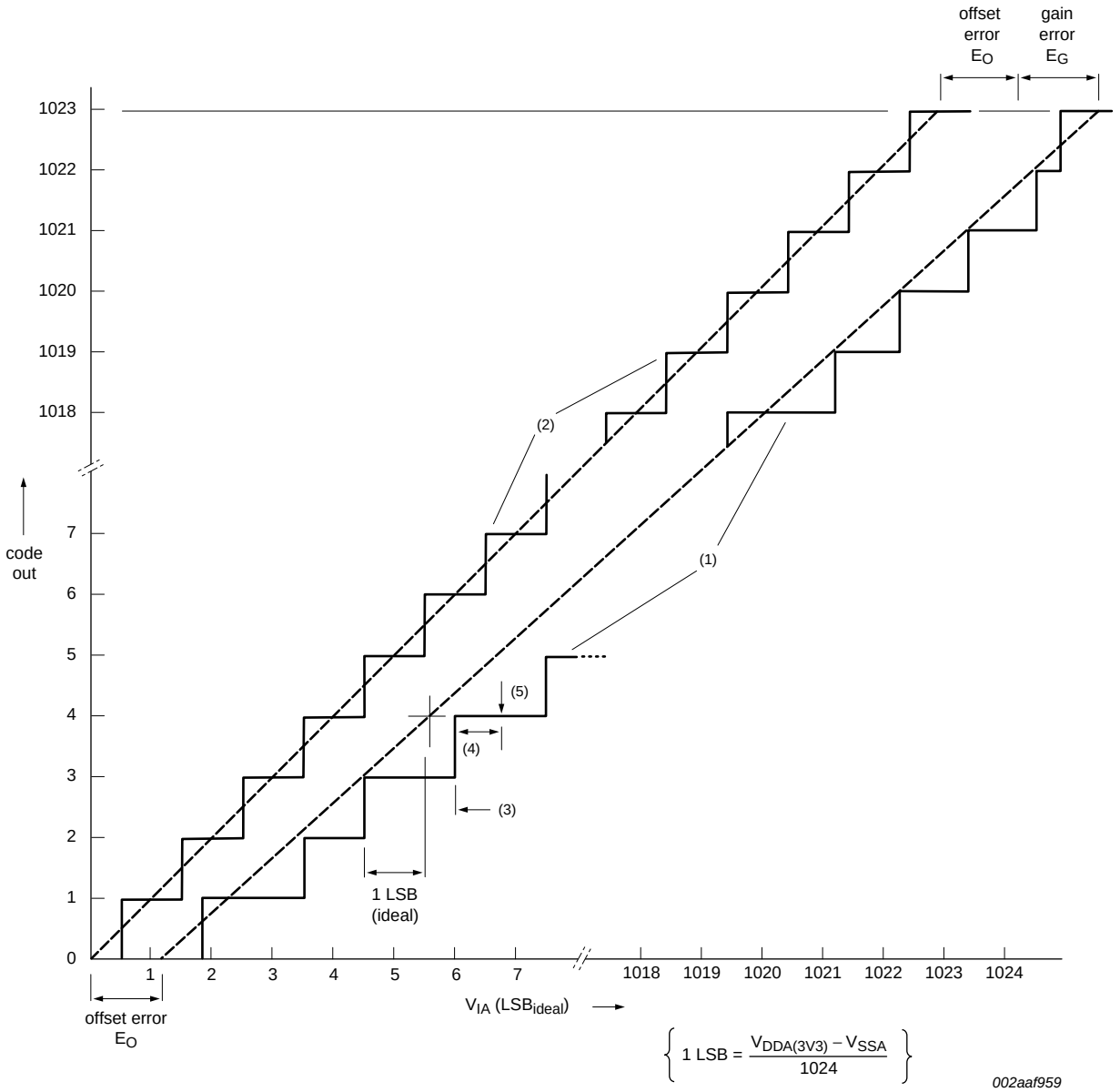


Fig 36. External static memory read/write access (PB = 1)



(1) Example of an actual transfer curve.

(2) The ideal transfer curve.

(3) Differential linearity error (E_D).

(4) Integral non-linearity ($E_{L(adj)}$).

(5) Center of a step of the actual transfer curve.

Fig 41. 10-bit ADC characteristics

Table 44. Recommended values for $C_{X1/X2}$ in oscillation mode (crystal and external components parameters) low frequency mode

Fundamental oscillation frequency	Maximum crystal series resistance R_S	External load capacitors C_{X1}, C_{X2}
12 MHz	< 160 Ω	18 pF, 18 pF
	< 160 Ω	39 pF, 39 pF
16 MHz	< 120 Ω	18 pF, 18 pF
	< 80 Ω	33 pF, 33 pF
20 MHz	< 100 Ω	18 pF, 18 pF
	< 80 Ω	33 pF, 33 pF

Table 45. Recommended values for $C_{X1/X2}$ in oscillation mode (crystal and external components parameters) high frequency mode

Fundamental oscillation frequency	Maximum crystal series resistance R_S	External load capacitors C_{X1}, C_{X2}
15 MHz	< 80 Ω	18 pF, 18 pF
20 MHz	< 80 Ω	39 pF, 39 pF
	< 100 Ω	47 pF, 47 pF

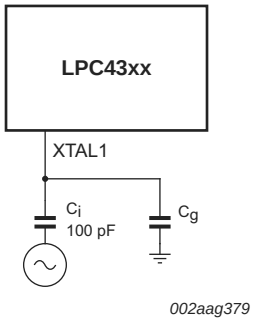


Fig 43. Slave mode operation of the on-chip oscillator

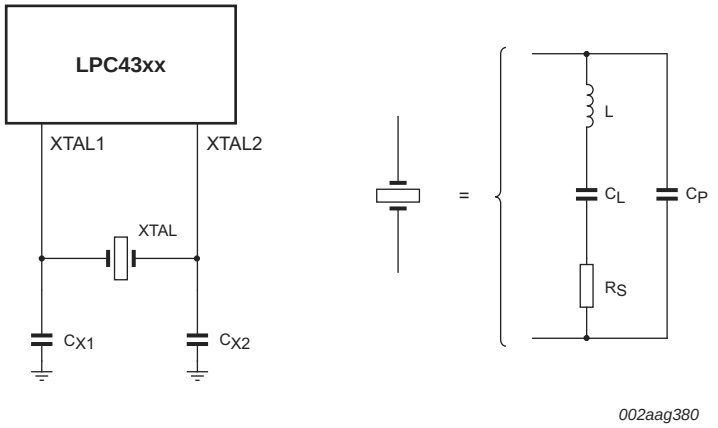
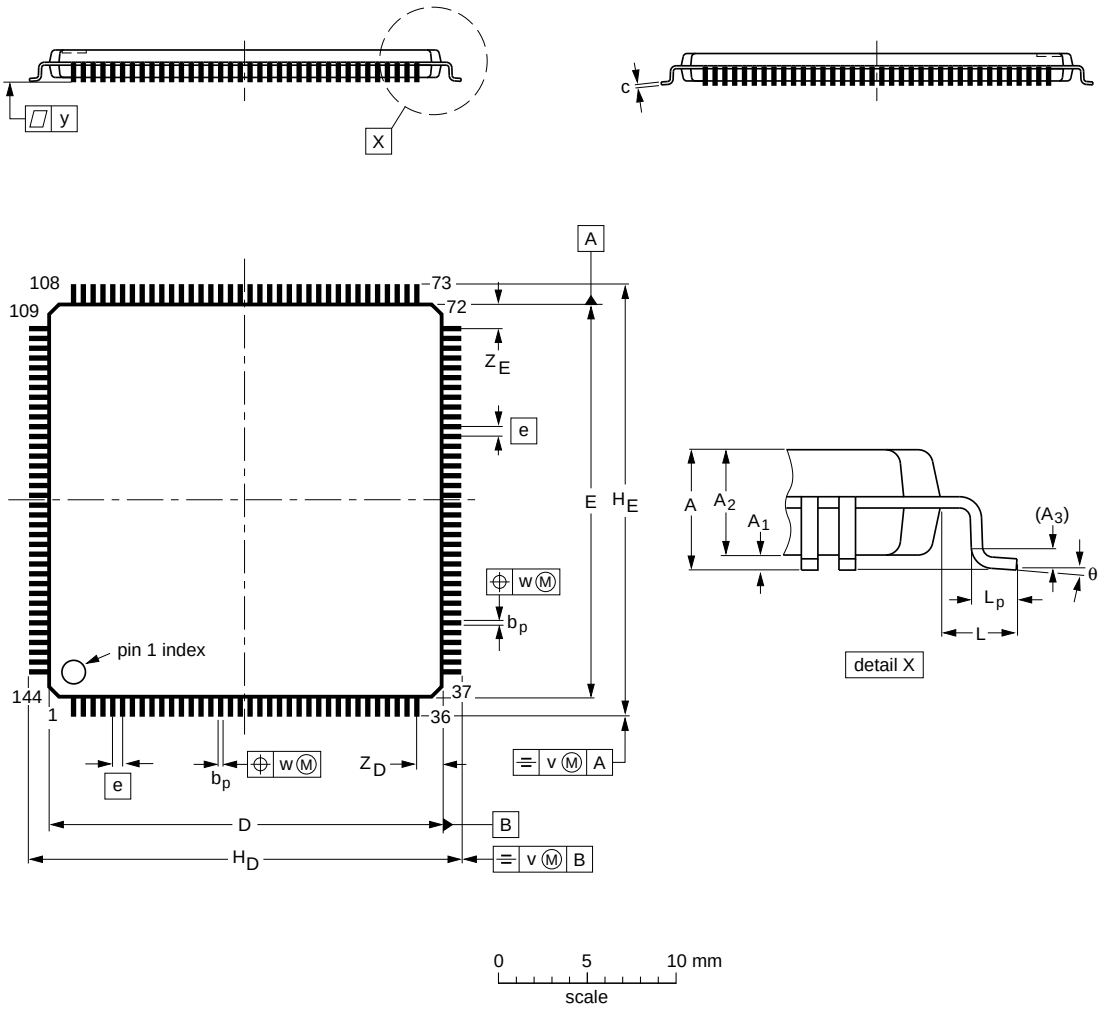


Fig 44. Oscillator modes with external crystal model used for C_{X1}/C_{X2} evaluation

LQFP144: plastic low profile quad flat package; 144 leads; body 20 x 20 x 1.4 mm **SOT486-1**



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(1)}$	e	H_D	H_E	L	L_p	v	w	y	$Z_D^{(1)}$	$Z_E^{(1)}$	θ
mm	1.6	0.15 0.05	1.45 1.35	0.25	0.27 0.17	0.20 0.09	20.1 19.9	20.1 19.9	0.5	22.15 21.85	22.15 21.85	1	0.75 0.45	0.2	0.08	0.08	1.4 1.1	1.4 1.1	7^o 0^o

Note

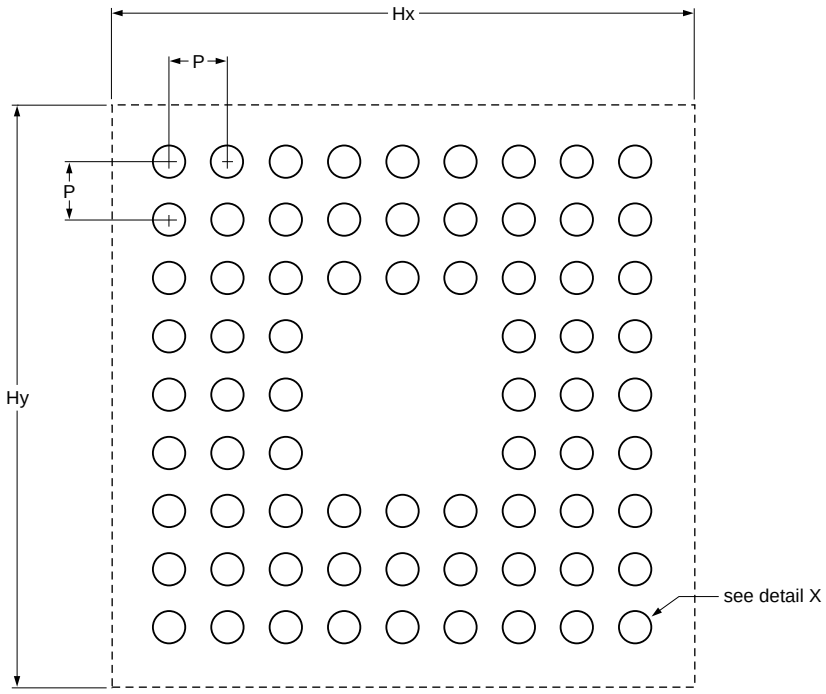
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT486-1	136E23	MS-026				~~00-03-14~~ 03-02-20

Fig 54. Package outline for the LQFP144 package

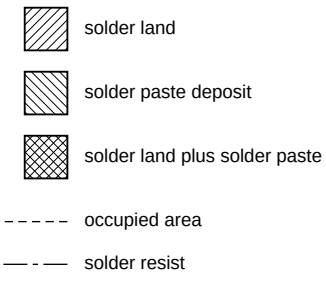
15. Soldering

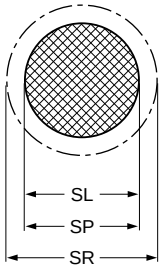
Footprint information for reflow soldering of LBGA256 package **SOT740-2**



Generic footprint pattern

Refer to the package outline drawing for actual layout





detail X

DIMENSIONS in mm

P	SL	SP	SR	Hx	Hy
1.00	0.450	0.450	0.600	17.500	17.500

sot740-2_fr

Fig 55. Reflow soldering of the LBGA256 package

Table 47. Revision history *…continued*

Document ID	Release date	Data sheet status	Change notice	Supersedes
Modifications:	• Updated Section 1 “General description”. • Minimum operating voltage changed from 2.2 V to 2.4 V for $V_{DD(REG)(3V3)}$, $V_{DD(IO)}$, $V_{DDA(3V3)}$, V_{BAT} in Table 11. • Operating temperature corrected in Table 27. Tamb = T_{amb} = -40 °C to 105 °C. • Max and min values of parameters t_{lag} and t_{lead} corrected for SSP master mode in Table 27. • Figure 32 “SSP in SPI mode and SPI slave timing” updated. • Typical values for parameters t_{DS}, t_{DH}, $t_{v(Q)}$, $t_{h(Q)}$ for SSP slave mode replaced by min and max numbers in Table 25. • Parameters t_{lead}, t_{lag}, and t_d added to SSP slave mode in Table 27. • SPIFI timing data restated for CL = 20 pF in Table 29 “Dynamic characteristics: SPIFI”. • USART timing added for master and slave mode in Figure 30 “USART timing”. • USB0_VBUS changed to input only. See Table 3 “Pin description”. • Changed the flash erase time (t_{er}) to 100ms. See Table 15. • Updated Dynamic characteristics: SD/MMC table. See Table 37. • Added Band gap characteristics table. See Table 14. • Updated Table 2: Motor control PWM instead of PWM. • Updated Dynamic characteristics: USB0 and USB1 pins (full-speed). See Table 34. • Added a table note: The values in the table have been calculated with WAITTURN = 0x0 in STATICWAITTURN register. See Table 31. • Added a remark to Table 34. • Updated Table 13 “BOD static characteristics[1]”. Removed BOD interrupt levels 0 and 1; removed Reset levels 0 and 1. Not applicable.			
LPC435X_3X_2X_1X v.4	20140819	Product data sheet	-	LPC435X_3X_2X_1X v.3

Table 47. Revision history *…continued*

Document ID	Release date	Data sheet status	Change notice	Supersedes
Modifications:	• SD/MMC timing data updated. See Table 35 “Dynamic characteristics: SD/MMC”. • IEEE standard 802.3 compliance added to Section 11.18. Covers Ethernet dynamic characteristics of ENET_MDIO and ENET_MDC signals. • SSP master mode timing diagram updated with SSEL timing parameters. See Figure 31 “SSP in SPI mode and SPI master timing”. • Parameters t_{lead}, t_{lag}, and t_d added in Table 25 “Dynamic characteristics: SSP pins in SPI mode”. • Parameter t_{CSLWEL} with condition PB = 1 corrected: (WAITWEN + 1) × $T_{cy(clk)}$ added. See Table 29 “Dynamic characteristics: Static asynchronous external memory interface”. • Parameter $t_{CSLBLSL}$ with condition PB = 0 corrected: (WAITWEN + 1) × $T_{cy(clk)}$ added. See Table 29 “Dynamic characteristics: Static asynchronous external memory interface”. • Removed restriction on C_CAN bus usage. See CAN.1 errata in Ref. 2. • General-purpose OTP size corrected.			
LPC435X_3X_2X_1X v.3	20121206	Preliminary data sheet	-	LPC4357_53_37_33 v.2.1
Modifications:	• TFBGA180 packages removed. • Part LPC432x and LPC431x added. • SCT dither engine added and SCT bi-directional event enable features added. • Figure 10 “Dual-core debug configuration” added. • T = 105 °C data added in Figure 20 to Figure 23. • Change symbol names and parameter names in Table 21. • Parameter I_{LH} updated for condition V_I = 5 V and T_{amb} = 25 °C/105 °C in Table 11. • Power consumption data added in Section 10.1. • SPIFI dynamic characteristics added in Section 11.16. • IRC accuracy corrected to ± 2 % for T_{amb} = -40 °C to 0 °C and T_{amb} = 85 °C to 105 °C. • Pull-up and Pull-down current data (Figure 24 and Figure 25) updated with data for T_{amb} = 105 °C. • SPIFI maximum data rate changed to 52 MB per second. • Recommendation for V_{BAT} use added: The recommended operating condition for the battery supply is $V_{DD(REG)(3V3)} > V_{BAT}$ + 0.2 V. • Table 14 “Band gap characteristics” added. • Section 7.23.9 “Power Management Controller (PMC)” added. • Description of ADC pins on digital/analog input pins changed. Each input to the ADC is connected to ADC0 and ADC1. See Table 3. • OTP memory size changed to 64 bit. • Use of C_CAN peripheral restricted in Section 2. • ADC channels limited to a total of 8 channels shared between ADC0 and ADC1.			
LPC4357_53_37_33 v.2.1	20120904	Preliminary data sheet	-	LPC4357_53_37_33 v.2
Modifications:	• SSP0 boot pin functions corrected in Table 5 and Table 4. Pin P3_3 = SSP0_SCK, pin P3_6 = SSP0_SSEL, pin P3_7 = SSP0_MISO, pin P3_8 = SSP0_MOSI. • SWD removed for ARM Cortex-M0. • BOD de-assertion levels added in Table 13. • Peripheral power consumption data added in Table 12. • Minimum value for all supply voltages changed to -0.5 V in Table 7.			